

**METHODS OF FORMING ELECTRONIC DEVICES INCLUDING DIELECTRIC  
LAYERS WITH DIFFERENT DENSITIES OF TITANIUM AND RELATED  
STRUCTURES**

ABSTRACT OF THE DISCLOSURE

Methods of forming an electronic device include providing a first electrode, providing a dielectric oxide layer on the first electrode, and providing a second electrode on the dielectric oxide layer so that the dielectric oxide layer is between the first and second electrodes. More particularly, a first portion of the dielectric oxide layer adjacent the first electrode can have a first density of titanium, and a second portion of the dielectric oxide layer opposite the first electrode can have a second density of titanium different than the first density. Related structures are also discussed.